Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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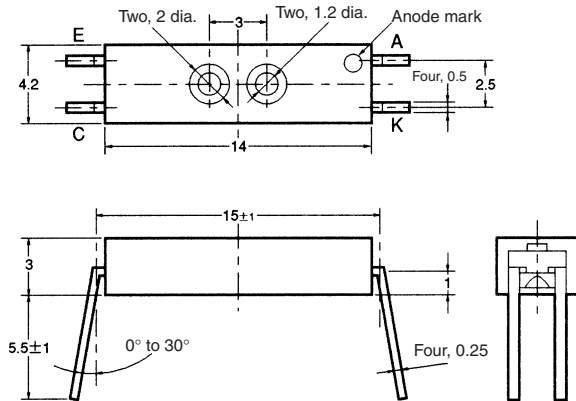Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

OMRON
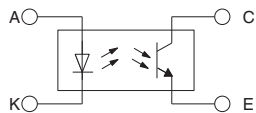
Photomicrosensor (Reflective)
EE-SY171

⚠ **Be sure to read *Precautions* on page 24.**

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

Two, 2 dia. — 3 — Two, 1.2 dia. — Anode mark
E — A
4.2
C — K
14
Four, 0.5 — 2.5

15±1
3
1
5.5±1 — 0° to 30° — Four, 0.25

Internal Circuit

A○───────○ C

K○───────○ E

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

■ Features

• 3-mm-tall, thin model
• Recommended sensing distance = 3.5 mm

■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rated value
Emitter	Forward current	I_F	50 mA (see note 1)
	Pulse forward current	I_{FP}	1 A (see note 2)
	Reverse voltage	V_R	4 V
Detector	Collector–Emitter voltage	V_{CEO}	30 V
	Emitter–Collector voltage	V_{ECO}	---
	Collector current	I_C	20 mA
	Collector dissipation	P_C	100 mW (see note 1)
Ambient temperature	Operating	Topr	−40°C to 85°C
	Storage	Tstg	−40°C to 85°C
Soldering temperature		Tsol	260°C (see note 3)

Note: 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.
    2. The pulse width is 10 μs maximum with a frequency of 100 Hz.
   **3.** Complete soldering within 10 seconds.

■ Electrical and Optical Characteristics (Ta = 25°C)

| Item		Symbol	Value	Condition
Emitter	Forward voltage	V_F	1.2 V typ., 1.5 V max.	I_F = 30 mA
	Reverse current	I_R	0.01 μA typ., 10 μA max.	V_R = 4 V
	Peak emission wavelength	λ_P	940 nm typ.	I_F = 20 mA
Detector	Light current	I_L	50 μA min., 500 μA max.	I_F = 20 mA, V_{CE} = 10 V White paper with a reflection ratio of 90%, d = 3.5 mm (see note)
	Dark current	I_D	2 nA typ., 200 nA max.	V_{CE} = 10 V, 0 ℓx
	Leakage current	I_{LEAK}	2 μA max.	I_F = 20 mA, V_{CE} = 10 V with no reflection
	Collector–Emitter saturated voltage	V_{CE} (sat)	---	---
	Peak spectral sensitivity wavelength	λ_P	850 nm typ.	V_{CE} = 10 V
Rising time		tr	30 μs typ.	V_{CC} = 5 V, R_L = 1 kΩ, I_L = 1 mA
Falling time		tf	30 μs typ.	V_{CC} = 5 V, R_L = 1 kΩ, I_L = 1 mA

Note: The letter "d" indicates the distance between the top surface of the sensor and the sensing object.
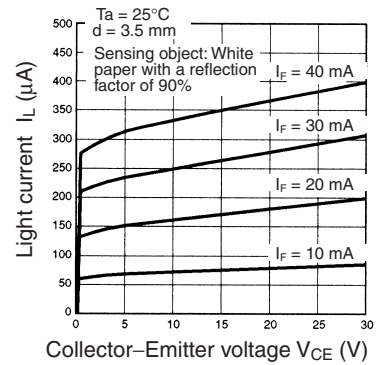
■ Engineering Data
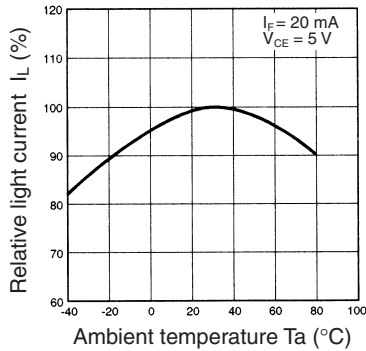
Forward Current vs. Collector Dissipation Temperature Rating
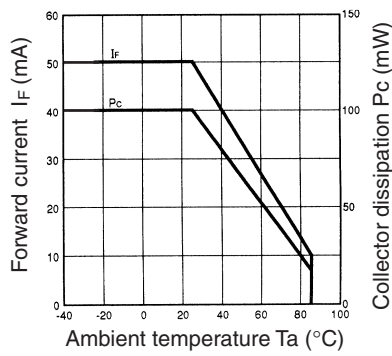
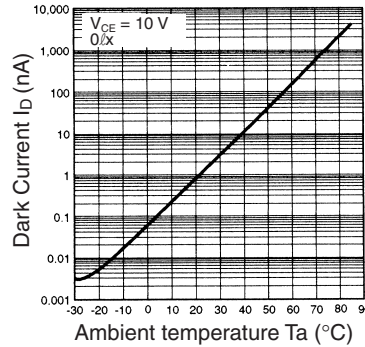**Light Current vs. Forward Current Characteristics (Typical)**
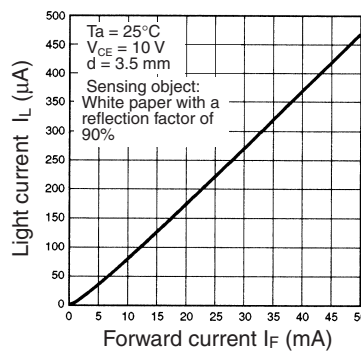
Light Current vs. Collector–Emitter Voltage Characteristics (Typical)
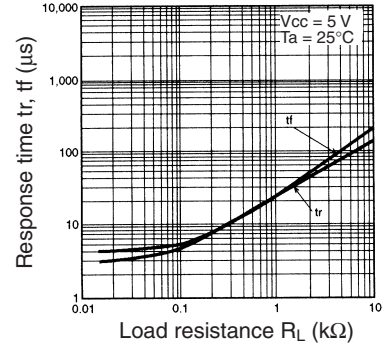

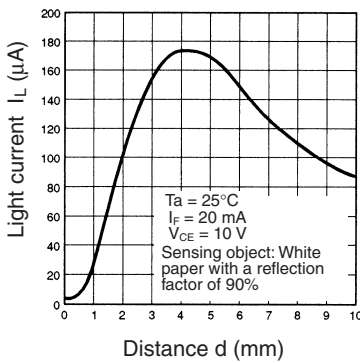**Relative Light Current vs. Ambient Temperature Characteristics (Typical)**

Dark Current vs. Ambient Temperature Characteristics (Typical)
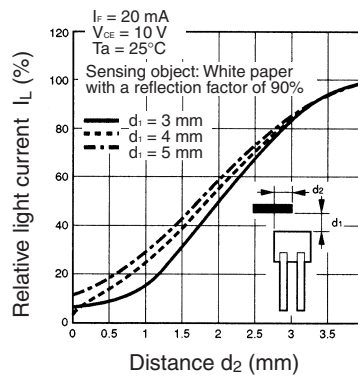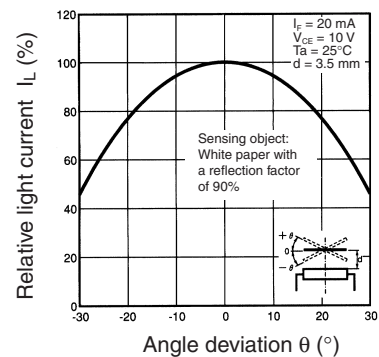

Response Time vs. Load Resistance Characteristics (Typical)

Sensing Distance Characteristics (Typical)

Sensing Position Characteristics (Typical)

Sensing Angle Characteristics (Typical)

Response Time Measurement Circuit